










	<h2 style="color: red;">JAN1N5811US</h2>	
	Manufacturer Part Number:	JAN1N5811US
	Manufacturer/Brand:	Microsemi
	Part of Description:	DIODE GEN PURP 150V 6A B-MELF
	Datasheets:	 JAN1N5811US.pdf
	RoHs Status:	Contains lead / RoHS non-compliant
<p>Image may be representation. See specs for product details.</p>	Stock Condition:	New original, Stock Available.
	Ship From:	Hong Kong
	Shipment Way:	DHL/Fedex/TNT/UPS/EMS

Specifications

Part Number	JAN1N5811US
Manufacturer	Microsemi
Description	DIODE GEN PURP 150V 6A B-MELF
Category	Discrete Semiconductor Products > Diodes - Rectifiers -
Part Status	Require For Quote & Check Stock
Voltage - Forward (Vf) (Max) @ If	875mV @ 4A
Voltage - DC Reverse (Vr) (Max)	150V
Supplier Device Package	B, SQ-MELF
Speed	Fast Recovery = 200mA (Io)
Series	Military, MIL-PRF-19500/477
Reverse Recovery Time (trr)	30ns
Packaging	Bulk
Package / Case	SQ-MELF, B
Operating Temperature - Junction	-65°C ~ 175°C
Mounting Type	Surface Mount
Diode Type	Standard
Current - Reverse Leakage @ Vr	5µA @ 150V
Current - Average Rectified (Io)	6A
Capacitance @ Vr, F	60pF @ 10V, 1MHz

JAN1N5811US Electronic Components is 100% New Original from YIC Distributor, Search JAN1N5811US Datasheets, PDF, Inventory at Y-IC.com Online, Order JAN1N5811US Microsemi with Warrantied and Confidence. Ship by DHL/FedEx/TNT/UPS Express. Support Payment with Telegraphic Transfer(T/T) or PayPal.
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<p>In:</p>  <p>JAN1N5816 Microsemi Corporation DIODE GEN PURP 150V 20A DO203AA</p>	 <p>JAN1N5816R MICROSEMI IGBT Modules</p>	 <p>JAN1N5809URS Microsemi Corporation DIODE GEN PURP 100V 3A BPKG</p>	 <p>JAN1N5811URS Microsemi Corporation DIODE GEN PURP 150V 3A BPKG</p>
 <p>JAN1N5811 Microsemi Corporation DIODE GEN PURP 150V 6A AXIAL</p>	 <p>JAN1N5809 Microsemi Corporation DIODE GEN PURP 100V 6A AXIAL</p>	 <p>JAN1N5816 Microsemi Corporation DIODE GEN PURP 150V 20A DO203AA</p>	 <p>JAN1N5814 Microsemi Corporation DIODE GEN PURP 100V 20A DO203AA</p>

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JAN1N5811US Price	JAN1N5811US Manufacturer	JAN1N5811US Picture	JAN1N5811US Stock	JAN1N5811US Inventory
JAN1N5811US New	JAN1N5811US Original	JAN1N5811US Warranted	JAN1N5811US RFQ	JAN1N5811US Order Online

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